Extreme-ultraviolet spectroscopy of highly charged xenon ions created using an electron-beam ion trap

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Extreme-ultraviolet spectra of xenon ions have been recorded in the 4.5 to 20 nm wavelength region using an electron beam ion trap and a flat field spectrometer. The electron beam energy was varied from 180 eV to 8 keV and radiation from charge states Xe^{6+} to Xe^{43+} was observed. Our measured wavelengths were compared to atomic structure calculations using the Cowan suite of codes. We have measured seventeen previously unreported features corresponding to transitions in Xe^{35+} through to Xe^{41+} with estimated wavelength uncertainties of ±0.003 nm. It was found that for the case of continuous injection of neutral xenon gas a wide range of charge states were always present in the trap but this charge state distribution was greatly narrowed, towards higher charge states, if a sufficiently low gas injection pressure was employed. The energy dependence of spectral lines arising from Xe^{42+} and Xe^{43+} revealed enhancement of the total ionization cross sections, due to excitation-autoionization of n=2 electrons to n=3 levels, in the Xe^{41+} and Xe^{42+} charge states.

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I. INTRODUCTION

It is well known that xenon ions produced under high temperature plasma conditions emit strongly in the extremeultraviolet (EUV) spectral range. The EUV spectrum of xenon arising from charge states Xe⁶⁺ to Xe¹⁰⁺ has been well documented due to observations of vacuum discharge plasmas and laser-produced plasmas [1-8]. Xenon has recently been earmarked as a possible source for EUV lithography due to radiation arising from the 4d-5p transition array in the Xe^{10+} ion, centered at 13.5 nm [5,9,10]. The charge states Xe^{11+} through to Xe^{17+} produce strong emission from 4d-4ftransitions that overlap in energy to produce an unresolved transition array (UTA) [11–15], centered near 11 nm. Radiation from this transition array was observed previously at the National Institute of Standards and Technology Electron Beam Ion Trap (NIST EBIT) and has been reported elsewhere $\begin{bmatrix} 16 \end{bmatrix}$.

EUV radiation from highly charged xenon ions has been observed in EBIT spectra by other groups as well. Träbert *et al.* [17] have reported wavelengths of prominent lines arising from 3s-3p transitions in Xe⁴²⁺ and Xe⁴³⁺ as well as lines from *B*-like, Be-like, and Li-like xenon ions. Träbert *et al.* [17] measured the $3s^{2} {}^{1}S_{0}$ - $3s3p {}^{1}P_{1}$ and $3s {}^{2}S_{1/2}$ - $3p {}^{2}P_{3/2}$ spectral lines of Xe⁴²⁺ and Xe⁴³⁺, respectively, using an electron beam energy of 20 keV, while spectral lines from higher charge states up to Li-like were measured using a beam energy of 133 keV. All these lines were observed in the 4 nm to 20 nm wavelength region, which is very similar to the wavelength range studied in this work. In their experiments, neutral xenon gas was continually injected into the trap region by means of a ballistic gas injector. Biedermann *et al.* [18] have studied the spectral range between 9 and 25 nm and they observed lines from 4*p*-4*d* transitions in ions Xe¹⁷⁺ through to Xe^{20+} , lines from 4p-4d and 4s-4p transitions in Xe^{21+} to Xe^{23+} as well as the well known 4s-4p transitions in Xe^{24+} and Xe^{25+} . Neutral xenon was continually fed into the trap region and the electron beam energy was varied from 434.2 eV for the Xe^{17+} spectrum up to 855.5 eV for the Xe^{25+} spectrum. Biedermann *et al.* [18] compared their wavelengths and intensities to those calculated by the HUL-LAC suite of codes [19].

At the NIST EBIT we have trapped and observed radiation from a wide range of xenon charge states as the electron beam energy was tuned from 180 eV up to 8 keV. As the electron beam energy was increased above the ionization threshold to produce a particular ion, we could observe emission from that ion stage. Spectra obtained at successive electron beam energies were overlaid and we compared the spectral features with published line lists as well as with atomic structure calculations performed at University College Dublin using the Cowan suite of codes. The result is a listing of emission lines from ions Xe^{6+} up to Xe^{43+} between 4.5 and 20 nm, including wavelengths, observed relative intensities, and some identifications along with a presentation of the relevant spectra. A total of forty seven spectra, taken under different conditions, were analyzed in this work.

II. EXPERIMENT

The EBIT is a versatile source capable of producing nearly any ion charge state [20]. It consists of a tightly focused electron beam that serves to create, trap, and excite highly charged ions. The electron beam energy is tunable, thus allowing good charge state selectivity. A superconducting Helmholtz-pair magnet provides a 3 T axial magnetic flux density that compresses the electron beam to a radius of about 30 μ m. The electron beam is accelerated through a set of three copper electrodes or drift tubes, the outer two held at a positive potential with respect to the inner one. Neutral gas is then injected into the middle drift tube region where the ions are formed by interaction with the electron beam. The

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positive ions are then trapped by a combination of the negative space charge of the electron beam, the axial potential well formed by the drift tubes, and the axial magnetic field. In the trapping region, the electron beam energy is determined by the potential applied to the middle drift tube.

After collisional excitation with the electron beam the radiation emitted from the plasma is viewed through a side window orientated at 90° to the electron beam direction. A flat field EUV spectrometer [21], based on the design of Kita *et al.* [22] was used in this work. This instrument has a very efficient light gathering capability while maintaining a high resolution. The EUV spectrometer was employed in this work to obtain spectra of xenon in the 4.5-20 nm range. The resolution of the spectrometer varies from 0.02 nm at 4 nm to 0.035 nm at 20 nm. Wavelength calibration was first performed by determining the central position (in pixels) of a number of well known transitions of xenon, argon, and neon ions injected into the EBIT at an electron beam energy of 8 keV, and then fitting a fourth-order polynomial to the calibration data. This calibration procedure along with a detailed list of the calibration lines used is presented in [21]. This calibration was applied to the spectra presented in Secs. IV A-IV D with the wavelength accuracy estimated to be ±0.02 nm across the spectral range. An improved calibration was obtained for the high energy data presented in Sec. IV E. This was done by using seven well known lines in the xenon spectrum. A Gaussian function was fitted to each line and its noninteger pixel center was found. This procedure was repeated for six different xenon frames taken on the same day and the collective statistical weight of the line positions were used to fit a dispersion function which could be applied to all xenon frames taken under the same EBIT operating conditions. This calibration was applied to the spectra presented in Sec. IV E giving an estimated accuracy of ± 0.003 nm. The detector used was a liquid nitrogen cooled, back-illuminated CCD consisting of an array of 1340 (horizontal) ×400 (vertical) pixels, operated in the spectroscopy mode. The spectroscopy mode allows binning of the 400 vertical pixels into a one-dimensional row of 1340 pixels, resulting in improved signal to noise ratios. The spectra were corrected for cosmic ray events in postacquisition and typical integration times ranged from 3 to 30 min. All line intensities plotted or tabulated in this paper have been corrected for the spectrometer response function [21].

Xenon gas was injected continuously, typically at injector reservoir pressures of 6.7×10^{-3} to 1.2×10^{-2} Pa. During one particular experimental run, the gas injection pressure was lowered to 9.3×10^{-6} Pa. It should be noted that the gas pressure in the trap region is expected to be less than 10⁻⁹ Pa, for even the highest gas injection pressures employed. The pressure in the EBIT is much lower than that in the gas injector because the two are separated by a small tube, which limits the pumping speed on the gas chamber to much lower values than that provided to the EBIT chamber by its pumps (see Appendix for details of the gas injector setup). During acquisition of spectra for electron beam energies of 180 to 500 eV, the middle drift tube was biased at a constant potential of -100 V, relative to the two end electrodes. In all subsequent runs at electron beam energies greater than 500 eV, the middle drift tube was biased at -500 V relative to the end electrodes. The electron beam current was maximized at each value of beam energy.

Although the electron beam energy is determined by the center drift tube potential, the exact energy is somewhat less than this due to beam space charge defects. The electron beam space charge correction $V_{\rm sc}$ to the beam energy in EBIT is given, in eV, by $V_{\rm sc} \sim -5I_{\rm beam}/E_{\rm beam}^{1/2}$ [23], where $I_{\rm beam}$ is the beam current in mA at energy $E_{\rm beam}$, given in keV. For example, with a 8 keV, 130 mA electron beam, the magnitude of this correction is ~ -240 eV. This is an upper bound since $V_{\rm sc}$ does not contain the positive space charge of the trapped ions. The beam energies $E_{\rm beam}$ as quoted in Sec. IV of this paper have not been space charge corrected.

III. THEORY

The Hartree-Fock (HF) approximation with the Cowan code [24] was used to calculate theoretical spectra of transition probability (gA value) versus wavelength (λ) for a range of xenon ions, from Xe⁶⁺ to Xe⁴⁶⁺. The theoretical spectral lines were convolved with a Gaussian function of full width at half maximum appropriate to our flat field spectrometer resolution at that wavelength. The Gaussian functions were then summed to produce the theoretical spectrum for that ion stage. The resulting theoretical spectra were compared to the spectra obtained at successive beam energies and were used to aid the identification of spectral features in the experimental spectra. It should be noted that the calculations did not include optically forbidden transitions and generally only transitions from the ground state were included. Also, the population of the emitting level can be an important factor in the interpretation of EBIT data, and this may have more bearing on the observed line intensity than the gA value.

In order to optimize the output from the Cowan code, the Slater-Condon integrals (F^k, G^k, R^k) and spin-orbit integral (ζ) were adjusted to match the Cowan wavelengths to the previously reported wavelengths listed in Table I. The F^k, G^k, R^k integrals were adjusted *en bloc* with the spin-orbit integral adjusted separately. The ion stages Xe⁸⁺ to Xe¹⁷⁺ contain a 4d electron in their valence subshell and their spectra are dominated by 4d-4f transitions. Figure 1 shows the result of varying $\vec{F}^k, \vec{G}^k, \vec{R}^k$ from 70% to 90% of the HF value in the calculation of the Xe⁸⁺ spectrum. ζ was adjusted separately and a value of 99% of the HF value was found to be optimum. The well known $4d^{10}-4d^94f^1S_0-P_1$ line of Xe⁸⁺, reported by Churilov and Joshi [4], was used as the reference line and the absolute error between theory and experiment was calculated for each set of F^k, G^k, R^k . A minimum error of 0.09 nm was obtained with $F^k, G^k, R^k = 79\%$ and $\zeta = 99\%$ for this line. The excited configurations included in the Xe^{8+} spectrum were 4d-nf (n=4-8), 4d-np (n=5-8), 4p-nd (n=5,6), and 4p-ns (n=5,6) and transitions to the ground state $(4d^{10})$ were calculated. The values of $F^k, G^k, \overline{R^k} = 80\%$ and $\zeta = 99\%$ were found to best match the 4d-4f reported wavelengths for Xe⁹⁺ and Xe¹⁰⁺ ions and these values were used to calculate theoretical spectra for the ion stages up to Xe¹⁷⁺. For higher ion stages up to Xe³⁷⁺ the scaling factors of F^k , G^k , $R^k = 90\%$ and $\zeta = 99\%$ were found to yield the most accurate results. The scaling factors required

TABLE I. Theoretical and experimental spectral lines of Xe^{6+} to Xe^{9+} observed at the NIST EBIT at an electron beam energy of 180 eV. Observed intensities relative to the most intense line $(Xe^{8+} 4d^{10}-4d^94f^1S_0-^1P_1$ [4]) are listed in column 5 while column 8 lists the experimental wavelengths obtained by other authors. The $Xe^{9+} 4d-5p$ transition array between 14 and 15 nm was also observed, individual features of which are omitted from this table.

	Lower	Upper	NIST EBIT		Cowan ^a		Reported
Ion	level	level	$\lambda^b \; (nm)$	Rel. Int.	$\lambda (nm)$	$gA \ (10^{10} \ {\rm s}^{-1})$	$\lambda (nm)$
Xe ⁸⁺	$4d^{10} {}^{1}S_0$	$4d^96f^1P_1$	8.54	0.03	8.54	34	8.5420 ^c
Xe ⁸⁺	$4d^{10} {}^{1}S_0$	$4d^97p\ {}^3P_1$	8.85	0.02	8.85	7	8.8444 ^c
Xe ⁸⁺	$4d^{10} S_0$	$4d^95f^{1}P_1$	9.63	0.13	9.61	140	9.6449 ^c
Xe ⁸⁺	$4d^{10} {}^{1}S_0$	$4d^{9}6p \ ^{1}P_{1}$	10.28	0.02	10.29	12	10.2815 ^c
Xe ⁸⁺	$4d^{10} {}^{1}S_{0}$	$4d^{9}6p^{3}P_{1}$	10.38	0.02	10.39	9	10.3808 ^c
Xe ⁹⁺	$4d^{9} {}^{2}D_{5/2}$	$4d^{8}4f$ (887203) _{5/2} ^d	11.29	0.02	11.29	12	11.2714 ^c
Xe ⁹⁺	$4d^{9} {}^{2}D_{5/2}$	$4d^{8}4f$ (881539) _{3/2} ^d	11.35	0.03	11.32	441	11.3438 ^c
Xe ⁹⁺	$4d^{9} {}^{2}D_{5/2}$	$4d^{8}4f$ (874794) _{3/2} ^d	11.43	0.08	11.44	295	11.4312 ^c
Xe ⁹⁺	$4d^{9} {}^{2}D_{3/2}$	$4d^{8}4f$ (887203) _{5/2} ^d	11.49	0.47	11.50	1070	11.4880 ^c
Xe ⁹⁺	$4d^{9} {}^{2}D_{5/2}$	$4d^84f$ (870470) _{7/2} ^d			11.49	1450	11.4880 ^c
Xe ⁹⁺	$4d^{9} {}^{2}D_{3/2}$	$4d^{8}4f$ (881539) _{3/2} ^d	11.57	0.30	11.53	288	11.5632 ^c
Xe ⁹⁺	$4d^{9} {}^{2}D_{5/2}$	$4d^84f(864592)_{5/2}^{d}$			11.59	982	11.5661 ^c
Xe ⁸⁺	$4d^{10} {}^{1}S_0$	$4d^{9}4f^{1}P_{1}$	12.02	1	12.00	456	12.0133 ^c
Xe ⁷⁺	$5s^2S_{1/2}$	$4d^95s4f^2P_{3/2}$	12.32	0.31	12.56	563	12.3243 ^c
Xe ⁷⁺	$5s {}^{2}S_{1/2}$	$4d^95s4f^2P_{1/2}$			12.56	282	12.3265 ^c
Xe ⁶⁺	$5s^{2} S_0^{1}$	$4d^95s^24f^1P_1$			12.19	186	12.3242 ^e
Xe ⁸⁺	$4d^{10} {}^{1}S_0$	$4d^{9}4f^{3}D_{1}$	14.36	0.04	14.31	0.6	14.3614 ^c
Xe ⁸⁺	$4d^{10} {}^{1}S_0$	$4d^95p \ ^3D_1$	16.18	0.06	16.15	25	16.1742 ^c
Xe ⁸⁺	$4d^{10} {}^{1}S_0$	$4d^95p\ ^1P_1$	16.53	0.26	16.50	4	16.5323 ^c
Xe ⁷⁺	$5s {}^{2}S_{1/2}$	$4d^95s5p(5/2, {}^1P_1)_{3/2}{}^{\rm f}$	17.09	0.08	17.09	16	17.0856 ^g
Xe ⁷⁺	$5s^2S_{1/2}$	$4d^95s5p(3/2, {}^3P_2)_{1/2}^{f}$	17.60	0.08	17.61	0.7	17.5872 ^g
Xe ⁷⁺	$5s^2S_{1/2}$	$4d^95s5p(3/2, {}^3P_1)_{1/2}^{f}$	17.73	0.05	17.76	10	17.7258 ^g
Xe ⁷⁺	$5s^2S_{1/2}$	$4d^95s5p(3/2, {}^3P_1)_{3/2}{}^{\rm f}$	17.78	0.06	17.78	14	17.7707 ^g
Xe ⁷⁺	$5s^2S_{1/2}$	$4d^95s5p(3/2, {}^3P_0)_{3/2}{}^{\rm f}$	17.98	0.02	17.92	2	17.9656 ^g
Xe ⁷⁺	$5s {}^{2}S_{1/2}$	$4d^95s5p(3/2, {}^3P_0)_{3/2}{}^{\rm f}$	18.15	0.02	18.07	0.5	18.1670 ^g
Xe ⁶⁺	$5s^{2} {}^{1}S_{0}$	$4d^95s^25p\ ^3D_1$	18.21	0.02	18.19	3	18.1876 ^e
Xe ⁷⁺	$5s^2S_{1/2}$	$4d^95s5p(5/2, {}^3P_1)_{3/2}{}^{\rm f}$	18.44	0.09	18.31	1	18.4655 ^g
Xe ⁶⁺	$5s^{2} {}^{1}S_{0}$	$4d^95s^25p\ ^1P_1$	18.56	0.09	18.55	18	18.5438 ^e

^aScaling factors of F^k , G^k , $R^k = 80\%$ and $\zeta = 99\%$ were used in the calculations.

^bThe estimated uncertainty of the wavelengths measured at NIST in this table is ± 0.02 nm. ^cChurilov and Joshi [4].

^dNumbers in boldface represent the values of the excited configuration energy levels (in cm⁻¹) as listed by Churilov and Joshi [4].

^eKaufman and Sugar [2].

^fIn [3] the $4d^{9} {}^{2}D_{J_{1}}$ level was coupled to $5s5p {}^{1,3}P_{J_{2}}$ to form the final J state. The first term in brackets, e.g., $(5/2, {}^{1}P_{1})_{3/2}$ represents the J_{1} term with the second term representing the ${}^{1,3}P_{J_{2}}$ term. The subscript outside of the brackets denotes the final J state.

^gKaufman and Sugar [3].

for the ion stages of Xe³⁸⁺ to Xe⁴³⁺ were values of F^k , G^k , R^k =95% and ζ =99%. The scaling factors of 90% to 95% used in the calculation of the spectra for ion stages >Xe¹⁷⁺ are consistent with the value of 93% used by Morgan *et al.* [25] in their calculation of the Xe³²⁺ 3d⁴ ⁵D₂-⁵D₃ and the Ba³⁴⁺ 3d⁴ ⁵D₂-⁵D₃ ultraviolet or visible lines, and points to the general trend that the required percentage adjustment of the scaling factors becomes less with increasing

ion stage. Also, it seems this general trend remains true across the visible, ultraviolet, and EUV spectral regimes.

Figure 2(a) shows a comparison between our calculations and experiment for the 3p-3d transitions of the Xe²⁸⁺ ion as measured by Wyart *et al.* [26]. They used a tokamak as their light source and the quoted uncertainty of their wavelength measurements is 0.002 nm. Our calculations are shown (dashed line) to underestimate their line positions by a mean



FIG. 1. Comparison of calculated line position with known line position for the Xe⁸⁺ $4d^{10}$ - $4d^94f^{1}S_0$ - 1P_1 transition at 12.0133 nm [4]. The Slater integrals F^k , G^k , R^k were adjusted *en bloc* until the absolute error between theory and experiment was a minimum. The spin-orbit integral, ζ , was held at its optimum value of 99% of the HF value.

of 0.033 nm. Figure 2(b) compares our theoretical calculations for the 4s-4p transitions of Xe²¹⁺ to Xe²³⁺ to the prominent features of the same transitions observed in EBIT, with a quoted uncertainty of 0.0058 nm, by Biedermann *et al.* [18]. Our calculations are seen (dashed line) to overestimate their line positions by a mean of 0.05 nm. Similarly, our calculations for the $3s^{2} {}^{1}S_{0}$ - $3s3p {}^{1}P_{1}$ line of Xe⁴²⁺ and the $3s {}^{2}S_{1/2}$ - $3p {}^{2}P_{3/2}$ line of Xe⁴³⁺ agree with Träbert *et al.* [17] measurements (6.2875±0.0012 nm and 6.6574±0.0020 nm) to within 0.063 nm and 0.011 nm, respectively. Consequently, in the majority of cases, we feel confident in our Cowan calculations, to at least the 0.1 nm level of accuracy, and we have quoted our calculated wavelength values to one additional decimal point.



FIG. 2. Comparison of our Cowan calculations with experimentally known line positions from highly charged xenon. The above figure represents the difference between experiment and calculation for (a) the 3p-3d transitions of Xe²⁸⁺ and (b) the 4s-4p transitions of Xe²¹⁺ (\blacklozenge), Xe²²⁺ (\blacklozenge), and Xe²³⁺ (\blacksquare). The dashed lines in both plots represent the mean difference between our theoretical wavelengths and the experimental wavelengths of [18,26]. The 3p-3dtransitions are underestimated by 0.033 nm while the 4s-4p transitions are too large by a mean of 0.05 nm. Scaling factors of $F^k, G^k, R^k=90\%$ and $\zeta=99\%$ were used in the calculations.



FIG. 3. Spectra obtained at electron beam energies of 180 to 500 eV and a gas injection pressure of 1.2×10^{-2} Pa. The strongest feature in each of the above spectra is the Xe⁸⁺ 4d¹⁰-4d⁹4f¹S₀-¹P₁ transition at 12.02 nm [4]. The electron beam energy (E_{beam}) and current (I_{beam}) are listed in the figure for each spectrum. The 210 to 500 eV spectra are truncated to clearly show the labeled features. The identification of the lines observed at the electron beam energy of 180 eV are given in Table I.

IV. LINE SPECTRA AND ANALYSIS

A. 180 to 500 eV line spectra

Figure 3 shows the spectra obtained with electron beam energies of 180 to 500 eV at a gas injection pressure of 1.2 $\times 10^{-2}$ Pa. In each of these spectra the most intense line observed was the Xe⁸⁺ 4*d*-4*f* ${}^{1}S_{0}{}^{-1}P_{1}$ transition at 12.02 nm, previously reported at 12.0133 nm [4]. At 180 eV emission from ion stages Xe⁶⁺ to Xe⁹⁺ was observed. The spectral lines arising from these ion stages are well documented and Table I lists the features observed in the present work. At an electron beam energy of 210 eV the Xe¹⁰⁺ ion (produced at 202 eV) is present in the trap and we observed the 4d-4f and 4d-5p transition arrays centered at 11.17 and 13.51 nm, respectively. The spectrum at 230 eV shows an additional feature peaked at 10.96 nm which is 4d-4f emission arising from the Xe¹¹⁺ ion, predicted by our theoretical spectrum to peak at a wavelength of 10.97 nm. The energy required to produce Xe¹¹⁺ is 227 eV. All xenon ionization energies were taken from [27].

At the electron beam energy of 500 eV (at which the maximum charge state attainable was Xe^{17+}) the 4*d*-4*f* unresolved transition array (UTA) was fully evolved, with the lines from the lower ion stages still present. In fact, when the intensities of the Xe⁶⁺ to Xe⁹⁺ lines relative to the $Xe^{8+} 4d-4f^{1}S_{0}-P_{1}$ line were tracked from the beam energy of 180 eV through to 500 eV we found little or no change, suggesting that these charge distributions were not a strong function of beam energy under our experimental conditions. These relative intensities are listed in Table I for the electron beam energy of 180 eV. The line list presented in Table I confirms our wavelength calibration and highlights the general agreement between the calculated and observed wavelength values. A spectrum at 600 eV beam energy was acquired at a gas injection pressure of 6.7×10^{-3} Pa and electron beam current of 1.7 mA. The features of the spectrum are very similar to those of the 500 eV spectrum with



FIG. 4. The spectrum obtained at an electron beam energy of 800 eV and a gas injection pressure of 6.4×10^{-3} Pa. The highest ion stage attainable at this energy is Xe²⁴⁺. The $4s^2$ -4s4p 1S_0 - 1P_1 line of Xe²⁴⁺ [28] is observed at 16.45 nm. Also present are Xe²⁴⁺ 4*p*-4*d* lines. The strongest feature in the spectrum is the Xe⁸⁺ 4*d*¹⁰-4*d*⁹4*f* 1S_0 - 1P_1 transition at 12.02 nm [4].

Xe²⁰⁺ being the maximum charge state attainable at this energy. Biedermann *et al.* [18] measured lines of mostly weak to moderate strength from ions Xe¹⁷⁺ to Xe²⁰⁺ between 10.6 nm and 11.2 nm, using electron beam energies ranging from 434.2 eV (for the Xe¹⁷⁺ spectrum) up to 615.9 eV (for the Xe²⁰⁺ spectrum). These Xe¹⁷⁺ to Xe²⁰⁺ lines coincide with the strong 4*d*-4*f* emission from the Xe¹⁰⁺ to Xe¹⁷⁺ ions observed in our spectra between 10.6 and 11.2 nm and were therefore not observable in this work. The presence of this intense 4*d*-4*f* structure in our spectra, not observed by Biedermann *et al.* [18], is most likely due to differing gas pressures employed in the two experiments (see Sec. IV D).

B. 800 eV line spectrum

Figure 4 shows the spectrum acquired at an electron beam energy of 800 eV and a gas injection pressure of 6.4

 $\times 10^{-3}$ Pa. The maximum charge state attainable at this energy is Xe²⁴⁺, the energy required to produce this ion being 736 eV. When this spectrum was overlaid with the 600 eV spectrum we found seven features not common to both. The well known Xe²⁴⁺ $4s^2$ -4s4p 1S_0 - 1P_1 line [28] appeared very strongly at 16.45 nm in our 800 eV spectrum, the only Xe²⁴⁺ transition to the ground state predicted to radiate in the 4 to 20 nm wavelength range. This line was also observed to be very strong by Biedermann et al. [18] in their study. A total of four lines from the 4p-4d and 4s-4p transitions of the Xe²³⁺ ion were observed in our study. These lines appeared as moderate to very strong intensity in the spectrum of Biedermann et al. [18] at a beam energy of 700 eV. Biedermann et al. [18] also observed 4s-4p and 4p-4d lines from Xe^{22+} and Xe²¹⁺ using beam energies of 650 and 616 eV, respectively. These lines appeared as very weak to moderate intensity in their spectra and were predicted by our calculations but not observed in our work at all. Two additional features, not observed by Biedermann *et al.* [18] are present in our 800 eV spectrum at 13.26 and 13.63 nm. Our Cowan calculations predict the $4s^24p^2P_{3/2}$ - $4s^24d^2D_{3/2}$ line at 13.36 nm in Xe²³⁺ and the $4s^24p^2$ ³ P_2 - $4s^24p4d$ ¹ D_2 line at 13.66 nm in Xe²²⁺. Hacker et al. [29] have observed two strong lines from Xe^{24+} , arising from transitions (4p-4d) not to the ground state $(4s^2)$, that coincide with our measurements. Since our spectra contain none of the Xe²²⁺ features observed by Biedermann et al. [18], and we know (because of the strong $Xe^{24+} 4s^2 - 4s4p {}^1S_0 - {}^1P_1$ line) that a significant amount of Xe²⁴⁺ is present in our trap at 800 eV, we attribute the 13.66 nm line to the 4p-4d line of Xe²⁴⁺. Also, since the 13.26 nm line was not observed by Biedermann et al. [18], this line was deemed to be the other intense $Xe^{24+} 4p-4d$ line observed by Hacker et al. [29]. The wavelengths of 13.265 and 13.625 nm quoted by Hacker et al. [29], match our observations exactly. The observed lines of Xe²³⁺ and Xe²⁴⁺ from the 800 eV spectrum are listed in Table II.

TABLE II. Theoretical and experimental spectral lines of Xe^{23+} and Xe^{24+} observed at the NIST EBIT at an electron beam energy of 800 eV. The most intense line is $Xe^{8+} 4d^{10} - 4d^94f^{-1}S_0 - {}^1P_1$ [4] with the Xe^{23+} and Xe^{24+} line intensities listed relative to this line in column 5.

	Lower	Upper	NIST EBIT		Cowan ^a		Reported
Ion	level	level	$\lambda^b \; (nm)$	Rel. Int.	$\lambda (nm)$	$gA \ (10^{10} \ {\rm s}^{-1})$	$\lambda (nm)$
Xe ²³⁺	$4s^24p\ ^2P_{1/2}$	$4s^24d\ ^2D_{3/2}$	11.36	0.13	11.29	102	11.359 ^c
Xe ²⁴⁺	$4s4p \ {}^{3}P_{2}$	$4s4d^{3}D_{3}$	13.26 ^d	0.11	13.18	105	13.265 ^e
Xe ²⁴⁺	$4s4p \ ^{1}P_{1}$	$4s4d {}^{1}D_{2}$	13.63 ^d	0.16	14.19	58	13.625 ^e
Xe ²³⁺	$4s^24p\ ^2P_{3/2}$	$4s4p^{2} {}^{2}P_{3/2}$	16.07	0.04	16.04	61	16.050 ^c
Xe ²³⁺	$4s^24p\ ^2P_{1/2}$	$4s4p^{2} {}^{2}P_{1/2}$	16.26	0.13	16.28	26	16.247 ^c
Xe ²⁴⁺	$4s^{2} S_0$	$4s4p \ ^{1}P_{1}$	16.45	0.72	16.62	32	16.4412^{f}
Xe ²³⁺	$4s^24p\ ^2P_{1/2}$	$4s4p^2 {}^2D_{3/2}$	17.12	0.13	17.27	17	17.109 ^c

^aScaling factors of F^k , G^k , R^k =90% and ζ =99% were used in the calculations.

^bThe estimated uncertainty of the wavelengths measured at NIST in this table is ± 0.02 nm.

^cBiedermann *et al.* [18].

^dLines are blended with $Xe^{10+} 4d-5p$ features between 13 and 14 nm.

^eHacker et al. [29].

^fKaufman *et al.* [28].



FIG. 5. The spectrum obtained at an electron beam energy of 1 keV and a gas injection pressure of 6.5×10^{-3} Pa. The highest ion stage attainable at this energy is Xe²⁶⁺. The Xe²⁵⁺ 4s-4p²S_{1/2}-²P_{3/2} line [28] is observed at 17.41 nm. This is the only Xe²⁵⁺ transition to the ground state predicted to fall in the wavelength range studied in this work, while no Xe²⁶⁺ transitions to the ground state are predicted to occur in the same range. Weak Xe²⁵⁺ 4p-4d and 4d-4f lines are observed, the strongest of which is labeled in the above figure. The strongest feature in the spectrum is the Xe⁸⁺ 4d¹⁰-4d⁹4f¹S₀-¹P₁ transition at 12.02 nm [4].

C. 1 keV line spectrum

Figure 5 shows the spectrum acquired at an electron beam energy of 1 keV and a gas injection pressure of 6.5×10^{-3} Pa. The maximum charge state attainable at this energy is the closed outer 3*d* shell arrangement of Xe²⁶⁺, the energy required to produce this ion being 856 eV. After overlaying the 1 keV spectrum with that obtained at 800 eV, six prominent features not present in the lower energy spectrum were found. The well known Xe²⁵⁺ $3d^{10}4s$ -4p $^{2}S_{1/2}$ - $^{2}P_{3/2}$ line [28] appeared strongly at 17.41 nm in our spectrum. This is the only Xe²⁵⁺ transition to the ground state predicted to radiate in the 4 to 20 nm wavelength range. This line was also observed to be very strong by Biedermann *et al.* [18] in their study. No transitions to the ground state of the Xe²⁶⁺ ion are predicted to radiate in this wavelength range. In the ab-



FIG. 6. The spectrum obtained at an electron beam energy of 775 eV and a gas injection pressure of 9.1×10^{-6} Pa. The highest ion stage attainable at this energy is Xe²⁴⁺. The spectrum is dominated by emission from the Xe²⁴⁺ and Xe²³⁺ ions. The $4s^2-4s4p$ 1S_0 - 1P_1 line of Xe²⁴⁺ at 16.45 nm [28] is the strongest observed feature in the spectrum. The corresponding wavelengths and transitions are listed in Table II.

sence of any alternative line candidates with transitions to the ground state, a total of four lines from the 4p-4d and 4d-4f transitions of the Xe²⁵⁺ ion were identified in our study. These lines have been previously observed by Kaufman *et al.* [28]. The Xe²⁵⁺ lines observed in the 1 keV spectrum are listed in Table III. Also listed in Table III is a line which we observed at 13.91 nm with a relative intensity of 0.09. We calculated the $3d^94p-3d^94d^3F_4-^3G_5$ and $3d^94d-3d^94f^1D_2-^1D_2$ transitions in Xe²⁶⁺ to be at 13.89 nm and 13.86 nm, respectively. We tentatively attribute this line to the $3d^94p-3d^94d$ transition since it has a calculated wavelength which is in better agreement with the observed value and it also has a calculated gA value of 1.3×10^{12} s⁻¹ compared to 1.1×10^{11} s⁻¹ for the $3d^94d-3d^94f$ transition.

D. Effect of gas injection pressure

The spectrum of Fig. 6 was obtained with an electron beam energy of 775 eV and a gas injection pressure of 9.1

	Lower	Upper	NIST EBIT		Cowan ^a		Reported
Ion	level	level	$\lambda^b \; (nm)$	Rel. Int.	$\lambda \ (nm)$	$gA \ (10^{10} \ {\rm s}^{-1})$	$\lambda (nm)$
Xe ²⁵⁺	$3d^{10}4p {}^2P_{1/2}$	$3d^{10}4d^2D_{3/2}$	11.90	0.07	11.91	66	11.8935 ^c
Xe ²⁵⁺	$3d^{10}4d^2D_{3/2}$	$3d^{10}4f^2F_{5/2}$	13.04 ^d	0.06	13.06	79	13.0428 ^c
Xe ²⁵⁺	$3d^{10}4d^2D_{5/2}$	$3d^{10}4f^2F_{7/2}$	13.51 ^d	0.12	13.47	103	13.4852 ^c
Xe ²⁵⁺	$3d^{10}4p {}^2P_{3/2}$	$3d^{10}4d^2D_{5/2}$	13.84 ^d	0.14	13.80	77	13.8389 ^c
Xe ²⁵⁺	$3d^{10}4s {}^2S_{1/2}$	$3d^{10}4p {}^2P_{3/2}$	17.41	0.41	17.46	20	17.3938 ^c
Xe ²⁶⁺	$3d^94p {}^3F_4$	$3d^{9}4d^{3}G_{5}^{e}$	13.91	0.09	13.89	132	

TABLE III. Theoretical and experimental spectral lines of Xe^{25+} and Xe^{26+} observed at the NIST EBIT at an electron beam energy of 1000 eV. The most intense line is $Xe^{8+} 4d^{10}-4d^94f^1S_0-{}^1P_1$ [4] with the Xe^{25+} and Xe^{26+} line intensities listed relative to this line in column 5.

^aScaling factors of F^k , G^k , R^k =90% and ζ =99% were used in the calculations.

^bThe estimated uncertainty of the wavelengths measured at NIST in this table is ± 0.02 nm.

^cKaufman *et al.* [28].

^dLine blended with $Xe^{10+} 4d-5p$ features between 13 and 14 nm.

^eTentative assignment.

 $\times 10^{-6}$ Pa. The highest ion stage attainable at this energy is Xe^{24+} . This spectrum can be compared to that shown in Fig. 4, obtained at an electron beam energy of 800 eV but at the much higher gas injection pressure of 6.4×10^{-3} Pa. The effect of decreasing the gas injection pressure on the observed spectrum is immediately noticeable. The features of the higher pressure spectrum emanating from ion stages Xe⁶⁺ to Xe^{10+} , along with the 4*d*-4*f* features of the Xe^{11+} to Xe^{17+} UTA, are completely absent at the lower pressure. Instead, the lower pressure spectrum is dominated by lines arising from Xe^{24+} and Xe^{23+} ions. This reflects a change in the equilibrium charge balance in the EBIT with changing gas pressure, due mainly to the rate of charge exchange becoming much less at reduced pressures. The seven prominent features of the lower pressure spectrum arising from the Xe^{23+} and Xe^{24+} ions and labeled in Fig. 6, are those same lines identified in the higher pressure spectrum of Fig. 4 and listed in Table II. The line intensities at the different gas pressures can also be compared by looking at Fig. 4 and Fig. 6. The $4s^2-4s4p$ ${}^1S_0-{}^1P_1$ line of Xe²⁴⁺ at 16.45 nm is at least 10 times stronger at the lower pressure. The intensity ratio of the 4s-4p line of Xe²⁴⁺ to the 4s-4p isolated lines of Xe²³⁺ is about 7 at the higher pressure compared to approximately 10 at the lower pressure. This is attributed to a 40% increase in the number density of Xe^{24+} ions relative to Xe^{23+} as the pressure is reduced. Therefore, the effect of lowering the neutral gas injection pressure is to suppress the lower charge state ions present in the trap and shift the ion population toward the maximum energetically allowed by the electron beam.

E. 2 to 8 keV line spectra

The spectra listed in this section were acquired using a gas injection pressure of 6.7×10^{-3} Pa. By tuning the electron beam energy from 2 up to 8 keV, ion stages up to a maximum of Xe⁴⁶⁺ can be created in the trap. Calculations predict that the spectra obtained in this beam energy window should be largely dominated by 3p-3d transitions in the ion stages Xe^{27+} to Xe^{41+} with the strongest emission occurring between 4 and 7 nm. The 3*p*-3*d* emission predicted to occur between 4 and 4.5 nm was not visible in our data due to the reduced sensitivity of our spectrometer in this region. Figure 7 shows the predicted emission from the 3p-3d transition array, between 4.5 and 7 nm, for ion stages Xe^{27+} to Xe^{34+} . This 3p-3d emission is fused into a narrow band near 5 nm and shifts to longer wavelengths with increasing ionization. Spectra obtained for electron beam energies between 2 and 4 keV contain a large number of low intensity features arising from these transitions. Due to the large number of lines and their low intensities, coupled with the large spread of charge states present in the trap, the assignment of a given feature to a particular ion was not accomplished for these ion stages in this work. Figure 8 shows simulated spectra, based on the predictions of the Cowan code, for the ion stages Xe^{35+} up to Xe^{43+} . The spectra of these ion stages are predicted to contain fewer features than the spectra of the preceding eight ion stages. Consequently we found that at elec-



FIG. 7. Simulated spectra based on the predictions of the Cowan code for 3p-3d transitions in eight charge states of xenon. Each of the predicted lines was convolved with a Gaussian function of 0.02 nm width.

tron beam energies above 4 keV the spectra were greatly simplified, compared to those spectra obtained between 2 and 4 keV.

The spectra obtained between beam energies of 6 and 8 keV were very similar and contained the least number of features and we sought first to identify these. Figure 9 shows the 4.5 to 7 nm wavelength region of the spectrum taken at a beam energy of 8 keV. Figure 10 shows the same spectrum over the full wavelength range of 4.5 to 20 nm, with the uncertainty in the wavelength scale estimated to be 0.003 nm. We identified the Xe⁴²⁺ $3s^2$ -3s3p 1S_0 - 1P_1 and the $Xe^{43+} 2p^{6}3s-2p^{6}3p^{-2}S_{1/2}^{-2}P_{3/2}$ lines at 6.288 and 6.657 nm, respectively, observed previously in the spectra obtained from EBIT by Träbert et al. [17] at 6.2875±0.0012 nm and 6.6574±0.0020 nm. Seely et al. [30] measured a wavelength of 6.658 ± 0.003 nm for the Xe⁴³⁺ 2p⁶3s-2p⁶3p⁻²S_{1/2}-²P_{3/2} line based on laser plasma observations. We confirmed the presence of the Xe^{42+} and Xe^{43+} ions in the trap by observing two additional lines from these ions in our spectra. Our calculations predict the $2p^63s - 2p^63p^2S_{1/2} - {}^2P_{1/2}$ transition in Xe⁴³⁺ to emit at a wavelength of 12.38 nm. Reader et al. [31] extrapolated their data for lower ion stages to obtain leastsquares-fitted wavelengths for the Xe⁴³⁺ ion and they predicted a wavelength value of 12.3897 nm for this transition.



FIG. 8. Simulated spectra based on the predictions of the Cowan code for 3p-3d and 3s-3p transitions in nine charge states of xenon. Each of the predicted lines was convolved with a Gaussian function of 0.02 nm width.

We observed this line at 12.395 nm in our spectrum. We also calculated a wavelength of 13.35 nm corresponding to the $3s^2$ -3s3p 1S_0 - 3P_1 transition in Xe⁴²⁺. This line was previously measured at 12.993±0.003 nm by Seely *et al.* [32]



FIG. 9. A section of the spectrum obtained at an electron beam energy of 8 keV and a gas injection pressure of 6.7×10^{-3} Pa. The highest ion stage observed at this energy was Xe⁴³⁺. The features labeled X and Y are the broad features observed at 6.207 and 6.333 nm, respectively. A number of lines are predicted to contribute to these structures and these are listed in Table IV.



FIG. 10. The full spectrum obtained at an electron beam energy of 8 keV and a gas injection pressure of 6.7×10^{-3} Pa. Emission is observed from a wide range of charge states, from Xe⁶⁺ to Xe⁴³⁺. The strongest feature in the spectrum is the Xe⁸⁺ 4d¹⁰-4d⁹4f¹S₀-¹P₁ transition at 12.02 nm [4].

using a tokamak as their source. In addition, Ekberg *et al.* [33] fitted the difference between observed and calculated level energies in the magnesium-like ions of Mo, Rh, Ag, Cd, In, Sn, Sb, I, and Cs and interpolated these values to derive a fitted wavelength of 12.9916 nm for this $Xe^{42+} 3s - 3p^{-1}S_0 - {}^{3}P_1$ transition. This line was observed at a wavelength of 12.999 nm in our work. Reader *et al.* [31] also published fitted wavelengths corresponding to 3p-3d and 3d-4f transitions in the Xe^{43+} ion. These transitions are not to the ground state of the emitting ion and were not observed in this work. Consequently, all of the new assignments of the ground state of the emitting ion.

Table IV lists eighteen prominent features observed in the measured spectrum at 8 keV, arising from the ion stages Xe^{37+} through to Xe^{43+} . The Xe^{40+} and $Xe^{41+} 3p-3d$ lines, identified by Träbert et al. [17] from the calculations of Huang [34,35], were observed in this work at 5.007 and 5.213 nm, respectively. Our calculated wavelengths for these lines lie within 0.02 nm of those values predicted by Huang [34,35]. Träbert et al. [17] did not assign experimental wavelength values to these features. In most cases two or more lines were calculated with wavelengths that closely matched the observed wavelength. In these cases all of the strong calculated transitions were tabulated. For example, three strong Xe³⁹⁺ $3p^3$ - $3p^23d$ lines and a strong Xe³⁸⁺ $3p^4$ - $3p^33d$ line were calculated with wavelengths between 4.87 and 4.88 nm. As these lines coincide with the measured feature at 4.873 nm, this observed feature may contain a blend of the Xe³⁸⁺ and Xe³⁹⁺ calculated lines and the associated transitions are listed in Table IV. The features observed at 6.207 and 6.333 nm appear quite broad in the measured spectrum and these are likely to contain a mix of the corresponding calculated lines listed in Table IV. However, analysis suggests that the 6.207 nm feature may be predominantly due to the Xe³⁷⁺ $3p^5$ - $3p^43d^2P_{3/2}$ - $^4F_{5/2}$ transition since the observed feature was present more strongly at an electron beam energy of 3 keV, and seemed to gradually weaken as the beam energy was increased towards 8 keV. This seems to indicate that the observed feature is due to a lower ion stage than the

TABLE IV. Theoretical and experimental spectral lines of Xe^{37+} to Xe^{43+} observed at the NIST EBIT at an electron beam energy of 8 keV. The most intense line is $Xe^{8+} 4d^{10}-4d^94f^{-1}S_0^{-1}P_1$ [4], with line intensities listed relative to this line in column 5.

	Lower	Upper	NIST EBIT		Cowan ^a		Reported
Ion	level	level	$\lambda^b \; (nm)$	Rel. Int.	$\lambda \ (nm)$	$gA \ (10^{10} \ {\rm s}^{-1})$	$\lambda (nm)$
Xe ³⁸⁺	$3s^23p^{4}{}^3P_2$	$3p^{3}3d^{3}P_{2}$	4.783 ^c	0.13	4.77	420	
Xe ³⁸⁺	$3s^23p^{4} {}^{3}P_2$	$3p^{3}3d^{3}D_{3}$	4.813 ^c	0.11	4.81	513	
Xe ³⁸⁺	$3s^2 3p^{4} D_2^{1}$	$3p^33d^{-1}D_2$	4.846 ^d	0.08	4.84	116	
Xe ³⁹⁺	$3s^2 3p^3 {}^2P_{3/2}$	$3p^2 3d {}^4P_{3/2}$	4.873	0.25	4.87	378	
Xe ³⁹⁺	$3s^23p^3 {}^4S_{3/2}$	$3p^2 3d {}^2D_{3/2}$			4.87	204	
Xe ³⁹⁺	$3s^23p^3 {}^4S_{3/2}$	$3p^2 3d {}^2D_{5/2}$			4.88	134	
Xe ³⁸⁺	$3s^2 3p^{4} D_2$	$3p^{3}3d^{1}F_{3}$			4.88	488	
Xe ³⁹⁺	$3s^2 3p^3 {}^2P_{3/2}$	$3p^2 3d {}^4P_{5/2}$	4.955	0.10	4.96	338	
Xe ³⁹⁺	$3s^2 3p^{3} {}^2P_{1/2}$	$3p^2 3d {}^2D_{3/2}$			4.96	236	
Xe ³⁹⁺	$3s^2 3p^3 {}^2 D_{5/2}$	$3p^2 3d {}^2F_{7/2}$	4.980 ^e	0.07	4.99	384	
Xe ⁴⁰⁺	$3s^2 3p^2 {}^3P_0$	$3p3d^{3}D_{1}$	5.007	0.33	5.01	209	
Xe ⁴⁰⁺	$3s^2 3p^2 {}^3P_1$	$3p3d^{3}D_{2}$			5.01	122	
Xe ⁴⁰⁺	$3s^2 3p^2 {}^3P_1$	$3p3d {}^{3}P_{1}$			5.01	160	
Xe ⁴¹⁺	$3s^2 3p {}^2P_{1/2}$	$3s^2 3d {}^2D_{3/2}$	5.213	0.23	5.21	204	
Xe ⁴¹⁺	$3s^2 3p {}^2P_{3/2}$	$3s3p^2 {}^2P_{3/2}$	5.963	0.15	5.99	221	
Xe ⁴⁰⁺	$3s^2 3p^2 {}^3P_2$	$3s3p^{3}{}^{3}P_{2}$	6.158	0.20	6.14	225	
Xe ⁴¹⁺	$3s^2 3p {}^2P_{1/2}$	$3s3p^2 {}^2P_{1/2}$			6.16	75	
Xe ³⁷⁺	$3s^2 3p^5 {}^2P_{3/2}$	$3p^43d {}^4F_{5/2}$	6.207	0.12	6.21	108	
Xe ³⁹⁺	$3s^2 3p^{3} {}^2P_{3/2}$	$3p^2 3d {}^2D_{5/2}$			6.20	271	
Xe ³⁹⁺	$3s^2 3p^3 {}^2 D_{5/2}$	$3s3p^{4} {}^{2}D_{5/2}$			6.22	151	
Xe ⁴⁰⁺	$3s^2 3p^2 {}^1D_2$	$3s3p^{3}{}^{2}D_{2}$			6.19	120	
Xe ⁴¹⁺	$3s^2 3p \ ^2P_{3/2}$	$3s3p^{2} S_{1/2}^{2}$			6.18	51	
Xe ⁴²⁺	$3s^{2} S_{0}^{1}$	$3s3p \ ^{1}P_{1}$	6.288	0.43	6.32	90	6.2875^{f}
Xe ³⁸⁺	$3s^2 3p^{4\ 1}D_2$	$3p^{3}3d^{1}F_{3}$	6.333 ^g	0.21	6.32	130	
Xe ³⁹⁺	$3s^23p^3 {}^4S_{3/2}$	$3p^2 3d {}^4F_{5/2}$			6.31	137	
Xe ⁴⁰⁺	$3s^2 3p^2 {}^3P_0$	$3s3p^{3} {}^{3}D_{1}$			6.35	27	
Xe ⁴¹⁺	$3s^2 3p^{1\ 2}P_{1/2}$	$3s3p^2 {}^2D_{3/2}$	6.416	0.14	6.42	41	
Xe ³⁹⁺	$3s^23p^3 {}^4S_{3/2}$	$3s3p^{4} {}^{4}P_{3/2}$			6.42	44	
Xe ³⁸⁺	$3s^2 3p^{4} {}^3P_2$	$3p^{3}3d^{3}F_{3}$	6.459	0.08	6.47	91	
Xe ⁴³⁺	$3s^2S_{1/2}$	$3p {}^{2}P_{3/2}$	6.657	0.22	6.65	64	6.6574^{f}
Xe ⁴³⁺	$3s {}^2S_{1/2}$	$3p {}^{2}P_{1/2}$	12.395	0.21	12.39	5	12.3897 ^h
Xe ⁴²⁺	$3s^{2} S_{0}^{1}$	$3s3p {}^{3}P_{1}$	12.999	0.20	13.35	2	12.993 ⁱ

^aScaling factors of F^k , G^k , R^k =95% and ζ =99% were used in the calculations with the exception of the Xe³⁷⁺ ion calculations where a value of F^k , G^k , R^k =90% was employed.

^bThe estimated uncertainty of the wavelengths measured at NIST in this table is ±0.003 nm.

^cCalculations predict a number of lines from the Xe^{38+} ion that merge to form a 3p-3d structure unresolved in our spectra. The peak wavelengths are listed here along with the strongest predicted transitions falling within this structure.

^dThis feature is blended with the 4.873 nm line.

^eThis feature is blended with the 5.007 nm line.

^fTräbert *et al.* [17].

^gBroad structure.

^hReader *et al.* [31].

ⁱSeely et al. [32].

alternative ion stages of Xe^{39+} to Xe^{41+} , listed in Table IV, particularly as no emission from these higher ion stages was observed in the spectrum at 3 keV.

Although ions up to Xe^{46+} (with a production threshold of 7.89 keV [27]) were energetically possible at this beam energy no emission was observed from ion stages higher than

TABLE V. Theoretical and experimental spectral lines of Xe^{35+} to Xe^{37+} observed at the NIST EBIT at an electron beam energy of 4 keV. The most intense line is $Xe^{8+} 4d^{10}-4d^94f^1S_0-{}^1P_1$ [4], with line intensities listed relative to this line in column 5.

	Lower	Upper	NIST EBIT		Cowan ^a		Reported
Ion	level	level	$\lambda^b \; (nm)$	Rel. Int.	$\lambda (nm)$	$gA \ (10^{10} \ {\rm s}^{-1})$	$\lambda (nm)$
Xe ³⁵⁺	$3s^2 3d^{1\ 2}D_{5/2}$	$3p^53d^2 {}^4F_{5/2}$	5.760	0.12	5.76	140	
Xe ³⁵⁺	$3s^2 3d^{1\ 2}D_{3/2}$	$3p^53d^2 {}^4F_{5/2}$			5.76	175	
Xe ³⁷⁺	$3s^2 3p^{5} {}^2P_{1/2}$	$3p^4 3d {}^2P_{1/2}$			5.76	136	
Xe ³⁷⁺	$3s^2 3p^{5} {}^2P_{1/2}$	$3p^43d {}^2D_{3/2}$	6.045	0.07	6.04	98	
Xe ³⁶⁺	$3s^23p^{6} {}^1S_0$	$3p^53d {}^3D_1$			5.98	66	
Xe ³⁷⁺	$3s^2 3p^5 {}^2P_{3/2}$	$3p^43d \ ^4P_{3/2}$	6.265	0.08	6.30	54	

^aScaling factors of F^k , G^k , R^k =90% and ζ =99% were used in the calculations.

^bThe estimated uncertainty of the wavelengths measured at NIST in this table is ±0.003 nm.

Xe⁴³⁺. According to our calculations, there are no transitions from Xe⁴⁴⁺ and Xe⁴⁵⁺ ions to their ground state in the observed wavelength range. However, our calculations predict three $2s^22p^4-2s^2p^5$ transitions of the Xe⁴⁶⁺ ion at 4.68 nm $({}^{3}P_{0} - {}^{3}P_{1})$, 4.78 nm $({}^{3}P_{1} - {}^{3}P_{2})$, and 5.14 nm $({}^{1}D_{2} - {}^{3}P_{2})$. The absence of these lines is most likely due to the competing processes of ionization, recombination, and charge exchange that occur within the trap, resulting in insufficient Xe⁴⁶⁺ ions under our trap conditions. The cross section for radiative recombination increases with ion stage and serves to drive the charge balance in the trap to lower ion stages. The reverse is true for lower ion stages, where ionization is the dominant process, resulting in observed emission immediately as the ionization threshold is exceeded. The relatively high gas injection pressures employed in this work have also contributed to this effect, with the process of charge exchange driving the charge balance in the trap to lower ion stages.

worth noting is the absence of Also the $Xe^{40+} 3p^2 - 3p3d {}^1D_2 - {}^3D_2$ and ${}^1D_2 - {}^3D_3$ lines that should be unresolved in our spectrum with the resultant feature calculated to lie at 5.14 nm. This feature is predicted to be of similar strength to the other $Xe^{40+} 3p^2 - 3p3d$ feature observed strongly in our spectrum at 5.007 nm. We checked if the strong line observed at 5.213 nm, and identified as $Xe^{41+} 3s^2 3p - 3s^2 3d^2 P_{1/2} + 2D_{3/2}$, could be attributed to this Xe⁴⁰⁺ 3p-3d feature by adjusting the spin-orbit integral, ζ , up to 110% of its HF value as is sometimes necessary for highly charged ion calculations where relativistic effects are important. However, this adjustment resulted in the Xe^{40+} 3p-3d feature being shifted to a shorter wavelength and further away from the observed line position. A similar effect was found in the calculation of the well known 3s-3plines of Xe⁴²⁺ and Xe⁴³⁺. It was concluded that the scaling factor of $\zeta = 99\%$ is optimum for these calculations and the 5.213 nm feature, calculated at 5.21 nm, is correctly attributed to the $3s^23p-3s^23d {}^2P_{1/2}-{}^2D_{3/2}$ transition in the Xe⁴¹⁺ ion. The absence of the Xe⁴⁰⁺ 3p-3d feature may be due to the level population mechanisms in EBIT. Table V lists three features observed in our spectrum at a beam energy of 4 keV. These lines were either absent or present only very weakly in the spectra at 8 keV. This suggests that these lines are due to ion stages lower than those contributing strongly to the 8 keV spectra. Calculations revealed six lines from the Xe^{35+} to Xe^{37+} ions that best agree with the observed wavelengths.

F. Excitation-autoionization of Xe⁴¹⁺ and Xe⁴²⁺

Figure 11 shows the electron beam energy dependence of the intensity of the (a) $Xe^{43+} 2p^{6}3s \cdot 3p^{2}S_{1/2} \cdot P_{3/2}$ and (b) $Xe^{42+} 3s^{2} \cdot 3s^{3}p^{-1}S_{0} \cdot P_{1}$ measured lines. These lines are labeled in bold in Figs. 9 and 10. Considering the Xe^{43+} line plotted in Fig. 11(a), this line is not present in the measured spectrum, within the one-sigma noise level, below a beam energy of about 3.9 keV, although the production threshold for this ion is 3.24 keV. Above 3.9 keV, the line intensity rises gradually towards a beam energy of about 4.5 keV, above which an abrupt increase in line intensity is observed towards about 5 keV. The absence of the Xe^{43+} line as its production threshold was exceeded, and up to an energy of 3.9 keV, is attributed to the process of charge exchange, pro-



FIG. 11. (a) Electron beam energy dependence of the intensity of the Xe⁴³⁺ $2p^{6}3s \cdot 2p^{6}3p^{2}S_{1/2} \cdot P_{3/2}$ line, measured at 6.657 nm. (b) Electron beam energy dependence of the intensity of the Xe⁴²⁺ $3s^2 \cdot 3s^2p^{-1}S_{0} \cdot P_1$ line, measured at 6.288 nm. These lines are labeled in bold in Figs. 9 and 10. The data are normalized to the electron beam current. The vertical lines represent the energy threshold for production of the charge states Xe⁴²⁺ (3.07 keV) and Xe⁴³⁺ (3.24 keV). The change in slope near 4.5 keV (~4.3 keV after space charge correction) is attributed to the onset of $2p \cdot 3l$ excitation autoionization. Error bars are at the one-sigma level.

ceeding at a much faster rate than the ionization of the preceding ion stage, at these energies, for the neutral gas densities employed in these experiments. This leads to the rapid quenching of the Xe⁴³⁺ ion for these energies. The ionization rate of Xe^{42+} (EI₄₂₊), peaking at about a factor of 2.5 above the threshold energy, begins to exceed the charge exchange rate of Xe^{43+} (CX₄₃₊) as the energy is increased above about 3.9 keV, resulting in observed emission from the Xe^{43+} ion. Calculations of EI_{42+} and CX_{43+} were found to predict this behavior, with the shape of the net rate $(EI_{42+}-CX_{43+})$ curve matching that of the observed intensity curve, between 3.9 and 4.5 keV. The absence of threshold behavior for this ion is contrary to what was observed at lower energies, where, for example, emission from the Xe¹¹⁺ ion was observed immediately as its production threshold was exceeded (Sec. IV A, Fig. 3).

The abrupt increase in slope at about 4.5 keV is attributed to the enhancement of the total ionization cross section by excitation autoionization of 2p electrons to the n=3 shell in Xe⁴²⁺. These measurements are consistent with calculated electron-impact ionization cross sections for Xe43+ into Xe44+ by Reed et al. [36], and subsequent EBIT measurements of the same ion by Schneider *et al.* [37]. These studies have shown that for beam energies above 4.3 keV it is possible to excite 2p electrons to the n=3 levels and produce autoionizing states of the Xe^{43+} ion. It was shown [36,37] that near the thresholds for these excitations the ionization cross section increases abruptly (by a factor of about 4, between 4 and 5 keV) due to the excitation-autoionization contributions to the total ionization cross section. Howald *et al.* [38] measured absolute electron-impact ionization cross sections in low-Z Mg-like ions and found that the relative magnitude of the indirect ionization process increases dramatically in comparison with the direct process along the isoelectronic sequence.

A similar intensity profile to Fig. 11(a) was observed in Fig. 11(b) for the $Xe^{42+} 3s^2-3s3p {}^1S_0{}^{-1}P_1$ line, measured at 6.288 nm, revealing both direct and indirect contributions to the total ionization cross section in Xe^{41+} .

The data of Fig. 11 is shown normalized to the electron beam current. Similar profiles were observed when the Xe⁴²⁺ and Xe⁴³⁺ line intensities were plotted relative to the strong $Xe^{8+} 4d^{10} - 4d^94f^1S_0 - {}^1P_1$ line at 12.02 nm. It should also be noted that the energy scale of Fig. 11 is not corrected for space charge defects in the electron beam. For a 4.5 keV, 108 mA electron beam, this correction is estimated to be \sim -250 eV. This is an upper bound as it does not include the positive space charge of the trapped ions. When this correction is applied to the beam energy in Fig. 11, the sharp increase in line intensity occurs at \sim 4.3 keV, for both curves, consistent with the excitation of a 2p electron to the n=3shell. While Reed *et al.* [36] predict the ionization cross section to increase in a series of abrupt steps corresponding to the n=2 electron excitations, the energy resolution of Fig. 11 is not sufficient to show this step structure in detail. However, the data for both Xe^{43+} and Xe^{42+} is consistent with the enhancement of the ionization cross section by excitation autoionization, in the Xe⁴²⁺ and Xe⁴¹⁺ ions.



FIG. 12. (Color online) Details of the EBIT gas injector setup. *P*1 is the gas injector reservoir pressure, with *P*2 typically two orders of magnitude smaller than this. Pb is the pressure measured outside of the trap region ($<10^{-9}$ Pa). Note that the actual background pressure inside the trap region will be less than Pb, due to cryopumping by the surrounding 4.2 K surfaces.

V. SUMMARY AND CONCLUSIONS

We have presented spectra of xenon in the 4.5 to 20 nm wavelength range, obtained from xenon ions trapped in an EBIT. With the EBIT's capability to selectively produce and excite particular ion stages, we could observe the radiation from a wide range of charge states. The present study has led to the identification of lines corresponding to transitions within the ions of Xe^{6+} up to Xe^{43+} . We have performed atomic structure calculations using the Cowan suite of codes and found that our calculations could deliver results within 0.07 nm of the accepted wavelengths in the majority of cases. Ion stages Xe^{27+} through to Xe^{34+} have been shown to produce complex spectra corresponding to 3p-3d transitions where the emission is fused into a narrow band near 5 nm and shifts to longer wavelengths with increasing ionization. Due to the complexity of the 3p-3d emission arising from these ion stages we did not seek to identify these features in our spectra. Instead, we sought to make assignments based on the emission from Xe^{35+} through to Xe^{46+} since these ions have a lower density of emitting features that do not overlap in energy and therefore could be resolved in our spectra. The calculations were used to identify seventeen new features corresponding to 3s-3p and 3p-3d transitions in the ion stages Xe³⁵⁺ through Xe⁴¹⁺. We found that our spectra contained a density of features greater than normally associated with EBIT spectra and often contained lines from a very wide range of charge states up to the maximum energetically allowed, at the electron beam energy. We presented a spectrum acquired at a beam energy of 800 eV that contained features from Xe^{6+} through to Xe^{24+} , and we showed that by reducing the gas injection pressure by approximately two orders of magnitude a spectrum dominated by radiation from the highest two energetically allowed ion stages could be obtained. We also observed the enhancement of the ionization cross sections of Xe41+ and Xe42+, by excitationautoionization of n=2 electrons to n=3 levels, by tracking the energy dependence of the intensities of spectral lines arising from the resulting Xe^{42+} and Xe^{43+} charge states. The line intensities were seen to increase sharply as the n=2excitation threshold was exceeded, consistent with an abrupt increase in the total ionization cross section at these energies. The suppression of the Xe^{42+} and Xe^{43+} ions as their production thresholds were exceeded, due to the dominant process of charge exchange under certain EBIT operating conditions, was also observed.

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APPENDIX: GAS INJECTOR SETUP

Details of the EBIT gas injector setup are shown in Fig. 12.

- [1] S. S. Churilov and Y. N. Joshi, Phys. Scr. 65, 35 (2002).
- [2] V. Kaufman and J. Sugar, J. Opt. Soc. Am. B 4, 1919 (1987).
- [3] V. Kaufman and J. Sugar, J. Opt. Soc. Am. B 1, 38 (1984).
- [4] S. S. Churilov and Y. N. Joshi, Phys. Scr. 65, 40 (2002).
- [5] S. S. Churilov, Y. N. Joshi, J. Reader, and R. R. Kildiyarova, Phys. Scr. 70, 26 (2004).
- [6] G. O'Sullivan, J. Phys. B 15, L765 (1982).
- [7] W. Svendsen and G. O'Sullivan, Phys. Rev. A 50, 3710 (1994).
- [8] G. Schriever, K. Bergmann, and R. Lebert, J. Vac. Sci. Technol. B 17, 2058 (1999).
- [9] M. A. Klosner and W. T. Silvast, J. Opt. Soc. Am. B 17, 1279 (2000).
- [10] EUV Sources for Lithography, edited by V. Bakshi (SPIE Press, Bellingham, WA, 2006).
- [11] P. Mandelbaum, M. Finkenthal, J. L. Schwob, and M. Klapisch, Phys. Rev. A **35**, 5051 (1987).
- [12] J. Bauche, C. Bauche-Arnoult, M. Klapisch, P. Mandelbaum, and J. L. Schwob, J. Phys. B 20, 1443 (1987).
- [13] C. Bauche-Arnoult and J. Bauche, Phys. Scr., T **T40**, 58 (1992).
- [14] G. O'Sullivan and P. K. Carroll, J. Opt. Soc. Am. **71**, 227 (1981).
- [15] P. K. Carroll and G. O'Sullivan, Phys. Rev. A 25, 275 (1982).
- [16] K. Fahy et al., J. Phys. D 37, 3225 (2004).
- [17] E. Träbert, P. Beiersdorfer, J. K. Lepson, and H. Chen, Phys. Rev. A 68, 042501 (2003).
- [18] C. Biedermann, R. Radkte, G. Fuβmann, J. L. Schwob, and P. Mandelbaum, Nucl. Instrum. Methods Phys. Res. B 235, 126 (2005).
- [19] A. Bar-Shalom, M. Klapisch, and J. Oreg, J. Quant. Spectrosc. Radiat. Transf. 71, 169 (2001).
- [20] J. D. Gillaspy, Phys. Scr., T T71, 99 (1997).
- [21] B. Blagojević et al., Rev. Sci. Instrum. 76, 083102 (2005).
- [22] T. Kita, T. Harada, N. Nakano, and H. Kuroda, Appl. Opt. 22,

512 (1983).

- [23] D. W. Savin, P. Beiersdorfer, S. M. Kahn, B. R. Beck, G. V. Brown, M. F. Gu, D. A. Liedahl, and J. H. Scofield, Rev. Sci. Instrum. 71, 3362 (2000).
- [24] R. D. Cowan, *The Theory of Atomic Structure and Spectra* (University of California Press, Berkeley, CA, 1981).
- [25] C. A. Morgan, F. G. Serpa, E. Takács, E. S. Meyer, J. D. Gillaspy, J. Sugar, J. R. Roberts, C. M. Brown, and U. Feldman, Phys. Rev. Lett. 74, 1716 (1995).
- [26] J. F. Wyart, C. Bauche-Arnoult, E. Luc-Koenig, and T. Group, Phys. Scr. 32, 103 (1985).
- [27] G. C. Rodrigues, P. Indelicato, J. P. Santos, P. Patté, and F. Parente, At. Data Nucl. Data Tables 86, 117 (2004).
- [28] V. Kaufman, J. Sugar, and W. L. Rowan, J. Opt. Soc. Am. B 5, 1273 (1988).
- [29] H. H. Hacker et al., Appl. Phys. B 73, 59 (2001).
- [30] J. F. Seely, C. M. Brown, U. Feldman, J. O. Ekberg, C. J. Keane, B. J. MacGowan, D. R. Kania, and W. E. Behring, At. Data Nucl. Data Tables 47, 1 (1991).
- [31] J. Reader, V. Kaufman, J. Sugar, J. O. Ekberg, U. Feldman, C. M. Brown, J. F. Seely, and W. L. Rowan, J. Opt. Soc. Am. B 4, 1821 (1987).
- [32] J. F. Seely, J. O. Ekberg, U. Feldman, J. L. Schwob, S. Suckewer, and A. Wouters, J. Opt. Soc. Am. B 5, 602 (1988).
- [33] J. O. Ekberg, U. Feldman, J. F. Seely, C. M. Brown, B. J. MacGowan, D. R. Kania, and C. J. Keane, Phys. Scr. 43, 19 (1991).
- [34] K. N. Huang, At. Data Nucl. Data Tables 34, 1 (1986).
- [35] K. N. Huang, At. Data Nucl. Data Tables 32, 503 (1985).
- [36] K. J. Reed, M. H. Chen, and D. L. Moores, Phys. Rev. A 42, 5315 (1990).
- [37] D. Schneider et al., Phys. Rev. A 42, 3889 (1990).
- [38] A. M. Howald, D. C. Gregory, F. W. Meyer, R. A. Phaneuf, A. Müller, N. Djuric, and G. H. Dunn, Phys. Rev. A 33, 3779 (1986).